NSN 5961-01-173-2713

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-173-2713 **Inclosure Material:** Plastic **Overall Length:** Between 14.23 millimeters and 16.51 millimeters **Terminal Length:** Between 12.7 millimeters and 14.73 millimeters **Overall Width:** Between 9.66 millimeters and 10.66 millimeters Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-22oab **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 8.00 amperes forward current, total rms horsepower metric and 80.00 amperes forward current, total rms watts **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No